

3 Quadrants High temperature Triacs

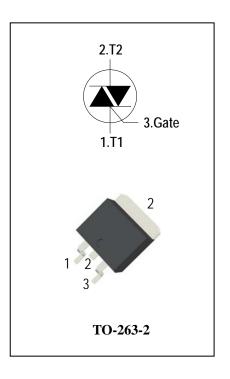
General Description

High current density due to mesa technology , guaranteed maximum junction temperature 150° C. The ADT20CH triac series is suitable for general purpose AC switching. They can beused as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers. The heatsink can be reduced,compared to traditional triacs, according to the high performance at given junction temperatures.

Features

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- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current (IT(RMS)= 20A)
- ♦ High Commutation dv/dt
- ◆ High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant



Absolute Maximum Ratings

Symbol	Items	Conditions		Ratings	Unit
V _{DRM}	Denetitive Deals Off Chate Valtage	T: 05°C	ADT20CH60G	600	V
V_{RRM}	Repetitive Peak Off-State Voltage	Tj = 25°C	ADT20CH80G	800	V
I _{T(RMS)}	R.M.S On-State Current	T _C = 129 °C	20	А	
I _{TSM}	Surge On-State Current	tp=20ms(50Hz)/tp=16.	210/220	А	
l ² t	I ² t for fusing	tp=10ms		265	A ² s
-11/-14	Critical rate of rise of on-state F = 120 Hz Tj = 150°C			50	A/µs
dl/dt	current	$I_G = 2 \times I_{GT}$, tr $\leq 100 \text{ ns}$			
I _{GM}	Peak Gate Current	tp = 20 μs Tj = 150°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=150°C)			1	W
P_GM	Peak Gate Power Dissipation(tp=20us,Tj=150°C)			10	W
T _j	Operating Junction Temperature			- 40 ~ 150	°C
T _{STG}	Storage Temperature			- 40 ~ 150	°C





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Electrical Characteristics(Tj = 25°C unless otherwise specified)

Symbol	Items		Conditions		ADT20CH60G/80G			Unit
					S	Blank	В	
I _{DRM}	Peak Forward Reverse Blocking		V _{DRM} = V _{RRM} , Tj = 25°C		5		uA	
I _{RRM}	Current		$V_{DRM} = V_{RRM}$, $Tj = 150$ °C	Max.	6.2			mA
V _{TM}	Peak On-S	tate Voltage	I _{TM} = 28A, t _p = 380 μs	Max.	1.5			V
$V_{\sf GD}$	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 150^{\circ}\text{C}$	Min.	0.15		V	
V_{GT}	Q1-Q2-Q3	Gate Trigger Voltage	1/ 40V D 000	Max.	1.3		V	
I _{GT}	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$, $R_L = 33\Omega$	Max.	10	35	50	mA
I _H	Q1-Q2-Q3	Holding Current	I _T = 0.1A	Max.	20	50	75	mA
	Q1-Q3	Latabina Cums = t	1 401	Max.	20	80	90	mA
ΙL	Q2	Latching Current	$I_G = 1.2 I_{GT}$		35	90	110	
dV/dt	Critical Rate of Rise of Off-State Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 150°C	Min.	500	1000	1500	V/µs
(dV/dt)c	Critical Rate of Change of Commutating Voltage		V_D =400V Tj = 150°C (dl/dt)c=-8.8A/ms	Min.	1	15	20	V/µs
R _{th(j-c)}	Junction to case (AC)		Max.	1		°C/W		
$R_{th(j-a)}$	Junction to ambient(Copper surface under tab:S=1cm²)		Max.	45			°C/W	

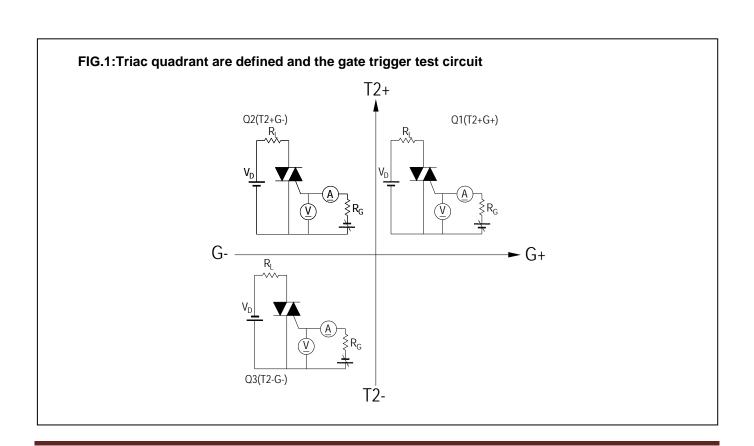




FIG.2: Maximum on-state power dissipation

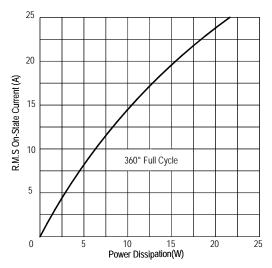


FIG.4: Maximum transient thermal impedance

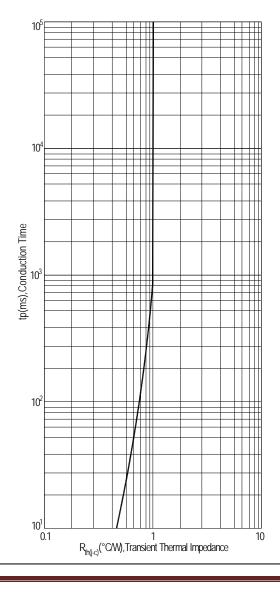


FIG.3: Typical RMS on-state current VS Allowable case Temperature

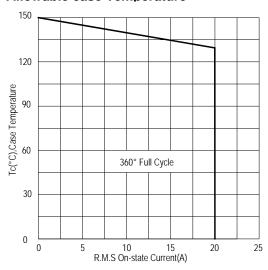


FIG.5: Rated surge on-state current (Non-Repetitive)

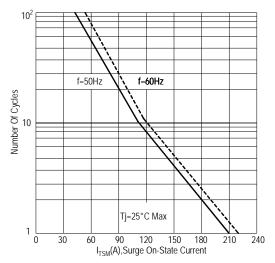
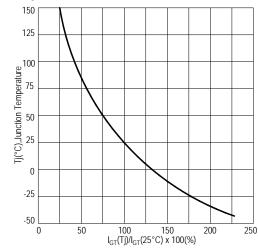


FIG.6: Gate trigger current VS Junction temperature





ADT20CH60G/80G

FIG.7:Holding current and Latching current VS Junction temperature

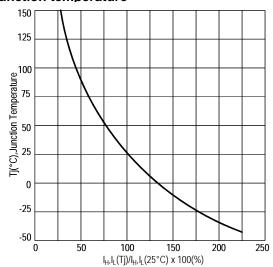


FIG.8: Gate trigger voltage VS Junction temperature

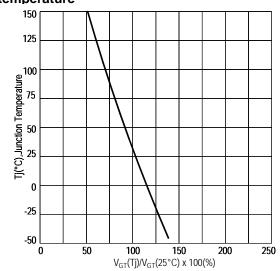
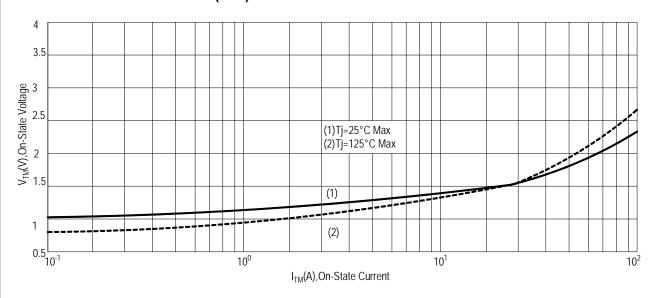


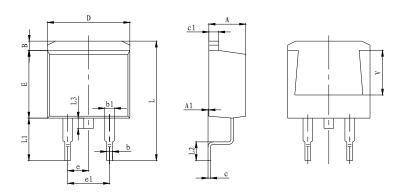
FIG.9: On-state characteristics(Max)



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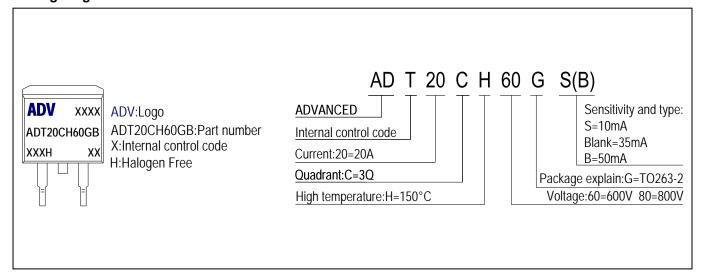


PACKAGE MECHANICAL DATA TO-263-2 Package Dimension



Cumb	Dimer	nsions	Dimensions			
Symb	In Milli	meters	In Inches			
ol	Min	Max	Min	Max		
Α	4.470	4.670	0.176	0.184		
A1	0.000	0.150	0.000	0.006		
В	1.170	1.370	0.046	0.054		
b	0.710	0.910	0.028	0.036		
b1	1.170	1.370	0.046	0.054		
С	0.310	0.530	0.012	0.021		
c1	1.170	1.370	0.046	0.054		
D	10.010	10.310	0.394	0.406		
Е	8.500	8.900	0.335	0.350		
е	2.540 TYP		0.100 TYP			
e1	4.980	5.180	0.196	0.204		
L	15.050	15.450	0.593	0.608		
L1	5.080	5.480	0.200	0.216		
L2	2.340	2.740	0.092	0.108		
L3	1.300	1.700	0.051	0.067		
V	5.600 REF		0.220 REF			

Making Diagram



Ordering information

Part number	Package	Marking	Packing	Quantity		
ADT20CH60G#	TO-263-2	ADT20CH60G#	Tube	50pcs		
AD120CH00G#			Embossed tape	800pcs		
ADT20CH80G#	TO-263-2	ADT20CH80G#	Tube	50pcs		
AD120CH60G#			Embossed tape	800pcs		
Note:# = Gate Trigger Current Sensitivity and type						



ADT20CH60G/80G

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